

Description

The DFI50FB12P3H2 offer lower losses and higher energy for application such as motor drive, inverter and soft switching applications.



Features

- 1200V50A, $V_{CE(sat)(typ.)} = 1.65V$
- Lower losses and higher energy
- Excellent short-circuit capability

Applications

- Motor drive
- Inverter
- Welding machines
- UPS

Circuit diagram

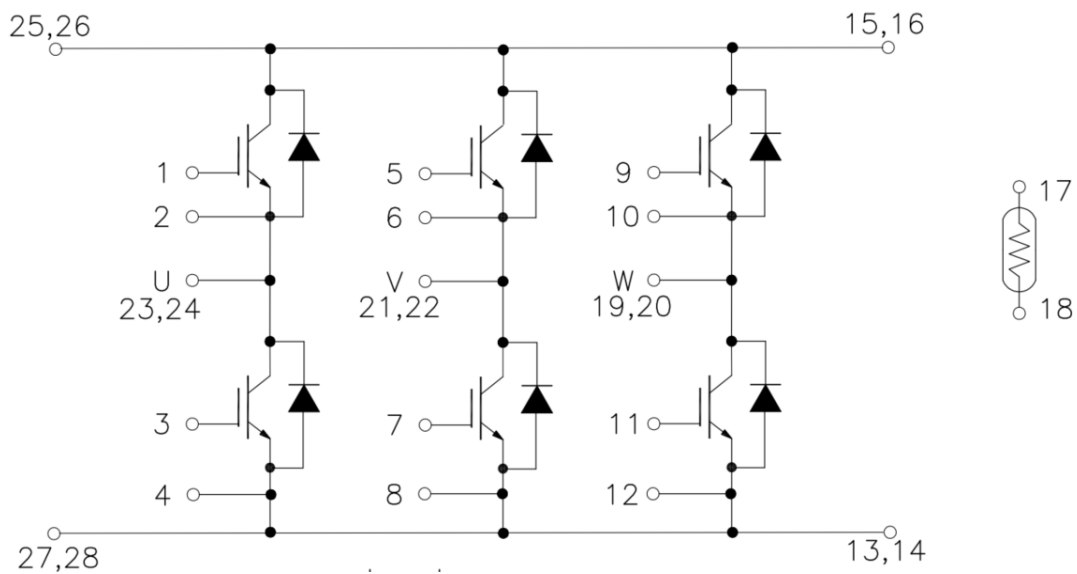


Figure 1. Out drawing & circuit diagram for DFI50FB12P3H2

Pin Configuration and Marking Information

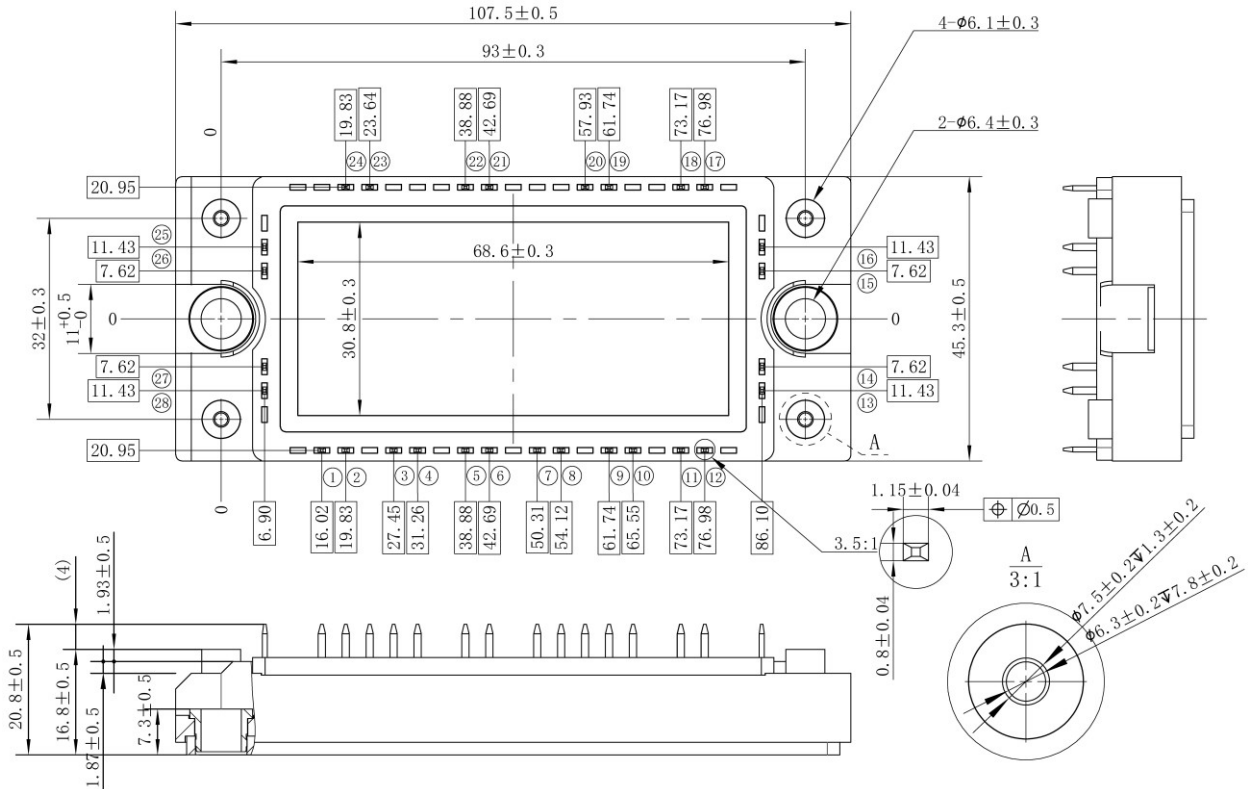


Figure 2. Pin configuration

Module

Parameter	Conditions	Value	Unit
Isolation Voltage	RMS, $f = 50\text{Hz}$, $t = 1\text{min}$	2.5	KV
CTI	-	>200	-
Module lead resistance, terminals – chip	$T_c = 25^\circ\text{C}$	0.8	m Ω
Mounting torque for module mounting	M5	3 to 6	Nm
Weight	-	175	g

Maximum Ratings (IGBT, Freewheeling Diode , $T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
V_{CES}	Collector-Emitter Voltage	G-E Short	1200	V
V_{GES}	Gate-Emitter Voltage	C-E Short	$\pm 20\text{V}$	V
I_C	DC Continuous Collector Current	$T_C=110^{\circ}\text{C}$	50	A
I_{CM}	Pulse Collector Current	$t_p=1\text{ms}$, Note1	100	A
P_C	Maximum Power Dissipation	$T_C=25^{\circ}\text{C}$, $T_j=175^{\circ}\text{C}$ (IGBT)	357	W
I_F	Diode forward Current	-	50	A
I_{FRM}	Repetitive peak forward Current	$t_p=1\text{ms}$, Note1	100	A
t_{sc}	Short Circuit Withstand Time	$V_{GE}=15\text{V}$, $V_{CE}=600\text{V}$, $T_j=150^{\circ}\text{C}$	10	us
T_{jmax}	Max junction temperature	-	175	$^{\circ}\text{C}$
T_{jop}	Operating junction temperature	-	-40 to 150	$^{\circ}\text{C}$
T_{stg}	Storage temperature	-	-40 to 125	$^{\circ}\text{C}$

Note1: Pulse width limited by maximum junction temperature

NTC characteristics

Symbol	Parameter	Condition	Value			Unit
			Min.	Typ.	Max.	
R_{25}	Resistance	$T_C=25^{\circ}\text{C}$	-	5	-	$\text{k}\Omega$
$\Delta R/R$	Deviation of R_{100}	$T_C=100^{\circ}\text{C}$, $R_{100}=493\Omega$	-5	-	5	%
P_{25}	Power dissipation	$T_C=25^{\circ}\text{C}$	-	-	20	mW
$B_{25/50}$	B-value	$R_2 = R_{25} \exp [B_{25/50}(1/T_2 - 1/(298,15 \text{ K}))]$	-	3375	-	K
$B_{25/80}$	B-value	$R_2 = R_{25} \exp [B_{25/80}(1/T_2 - 1/(298,15 \text{ K}))]$	-	3411	-	K
$B_{25/100}$	B-value	$R_2 = R_{25} \exp [B_{25/100}(1/T_2 - 1/(298,15 \text{ K}))]$	-	3433	-	K

IGBT Electrical characteristics (T_j=25°C unless otherwise specified, chip)

Symbol	Item	Condition		Value			Unit	
				Min.	Typ.	Max.		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C =50A V _{GE} =15V	T _j =25°C	-	1.65	-	V	
			T _j =125°C	-	1.95	-	V	
			T _j =150°C	-	2.00	-	V	
V _{GE(th)}	Gate-Emitter threshold Voltage	I _C =2.8mA, V _{CE} =V _{GE}		5.0	5.8	6.5	V	
Q _G	Gate charge	V _{GE} = -15V to +15V		-	320	-	nC	
R _{Gint}	Internal gate resistor	f=1M	T _j =25°C	-	0	-	Ω	
C _{ies}	Input Capacitance	V _{CE} =25V, V _{GE} =0V f=1MHz	T _j =25°C	-	3.50	-	nF	
C _{oes}	Output Capacitance			-	0.45	-	nF	
C _{res}	Reverse transfer Capacitance			-	0.28	-	nF	
I _{CEs}	Collector- Emitter Cut off Current	V _{CE} =1200V, V _{GE} =0V		T _j =25°C	-	-	1	mA
I _{GES}	Gate-Emitter Leakage Current	V _{GE} =20V, V _{CE} =0V		T _j =25°C	-	-	200	nA
t _{d(on)}	Turn-on delay time	V _{CC} =600V I _C =50A V _{GE} =+15V/-8V R _{Gon} = R _{Goff} =15Ω Inductive load	T _j =25°C	-	72	-	ns	
			T _j =125°C	-	64	-		
			T _j =150°C	-	64	-		
t _r	Rise time		T _j =25°C	-	20	-	ns	
			T _j =125°C	-	24	-		
			T _j =150°C	-	26	-		
t _{d(off)}	Turn-off delay time		T _j =25°C	-	147	-	ns	
			T _j =125°C	-	155	-		
			T _j =150°C	-	164	-		
t _f	Fall time	T _j =25°C	-	279	-	ns		
		T _j =125°C	-	297	-			
		T _j =150°C	-	385	-			
E _{on}	Turn-on power dissipation	T _j =25°C	-	2.59	-	mJ		
		T _j =125°C	-	3.91	-			
		T _j =150°C	-	4.13	-			
E _{off}	Turn-off power dissipation	T _j =25°C	-	4.20	-	mJ		
		T _j =125°C	-	6.06	-			
		T _j =150°C	-	6.27	-			
R _{th(j-c)}	Thermal Resistance, Junction to Case (IGBT)			-	0.42	-	°C /W	
R _{th(c-s)}	Thermal Resistance, Case to sink (Conductive Grease applied) , Note1			-	0.20	-	°C /W	

Note1: Assumes Thermal Conductivity of grease is 2.8 W/m · K and thickness is 50um.

Freewheeling Diode Electrical characteristics (T_j=25°C unless otherwise specified, chip)

Symbol	Item	Condition	Value			Unit	
			Min.	Typ.	Max.		
V _F	Diode Forward Voltage	I _F =50A, V _{GE} =0V	T _j =25°C	-	1.63	-	V
			T _j =125°C	-	1.50	-	
			T _j =150°C	-	1.45	-	
t _{rr}	Diode Reverse Recovery Time	(Switch side) V _{CC} =600V, I _C =50A V _{GE} =+15V/-8V R _{Gon} = R _{Goff} =15Ω	T _j =25°C	-	245	-	ns
			T _j =125°C	-	392	-	
			T _j =150°C	-	434	-	
I _{RM}	Peak reverse recovery Current	(FRD side) V _{rr} =600V, I _F =50A V _{GE} =+15V/-8V Inductive load switching operation	T _j =25°C	-	62	-	A
			T _j =125°C	-	65	-	
			T _j =150°C	-	67	-	
Q _{rr}	Recovered charge	(FRD side) V _{rr} =600V, I _F =50A V _{GE} =+15V/-8V Inductive load switching operation	T _j =25°C	-	5.03	-	uC
			T _j =125°C	-	9.44	-	
			T _j =150°C	-	10.98	-	
E _{rr}	Reverse recovered energy	(FRD side) V _{rr} =600V, I _F =50A V _{GE} =+15V/-8V Inductive load switching operation	T _j =25°C	-	2.17	-	mJ
			T _j =125°C	-	4.19	-	
			T _j =150°C	-	4.86	-	
R _{th(j-c)}	Thermal Resistance, Junction to Case (Diode)		-	0.60	-	°C/W	
R _{th(c-s)}	Thermal Resistance, Case to sink (Conductive Grease applied), Note1		-	0.30	-	°C/W	

Note1: Assumes Thermal Conductivity of grease is 2.8 W/m · K and thickness is 50um.

Test Conditions

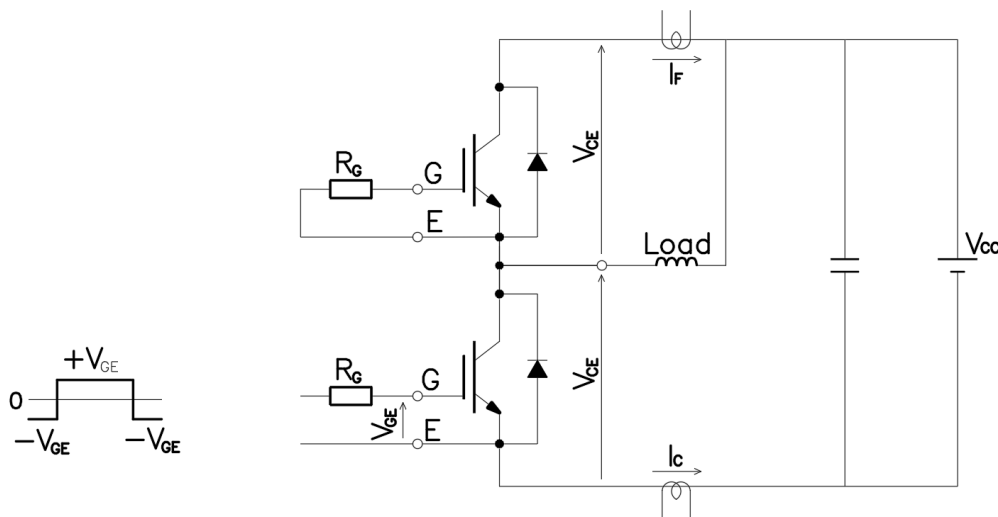


Figure 3. Switching time measure circuit

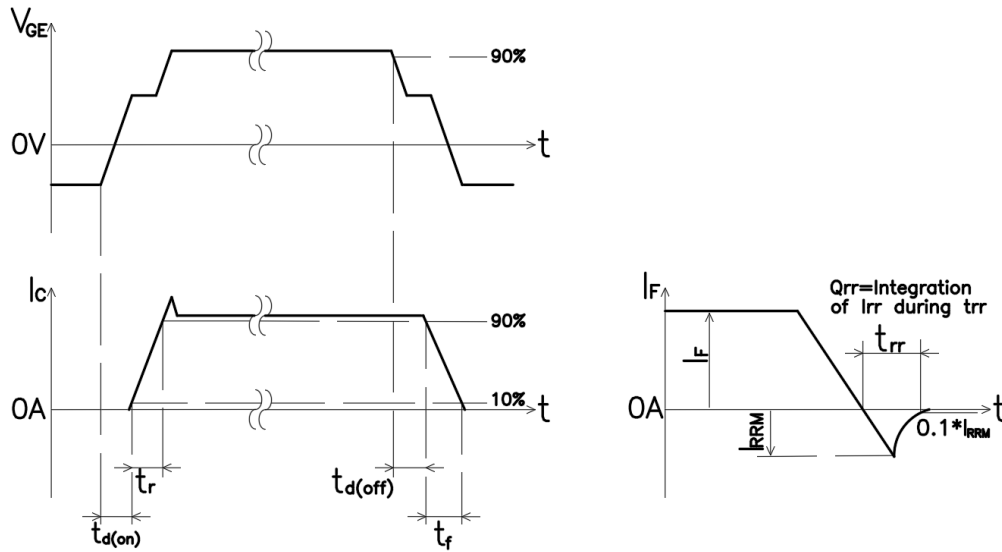
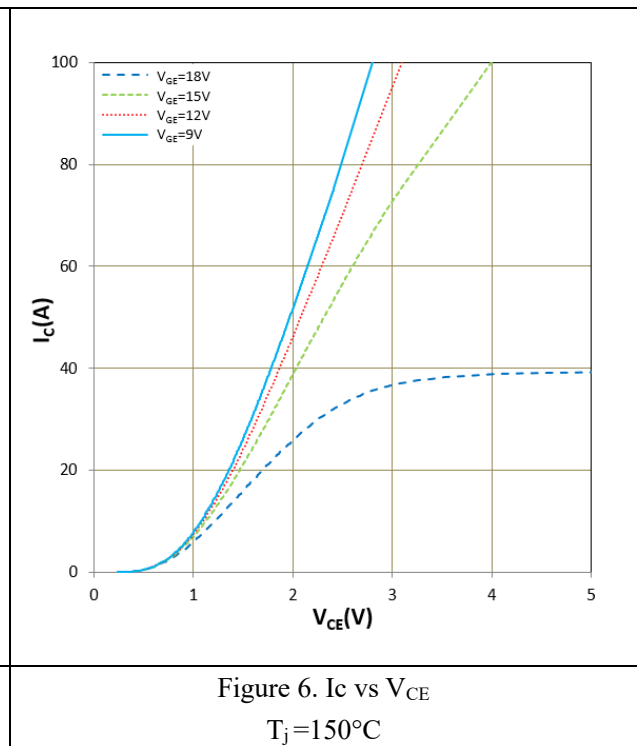
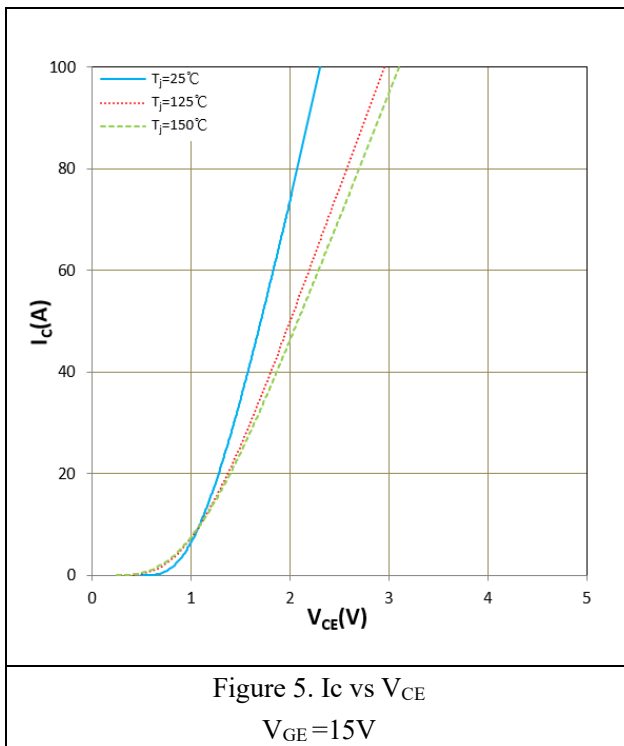


Figure 4. Switching time definition



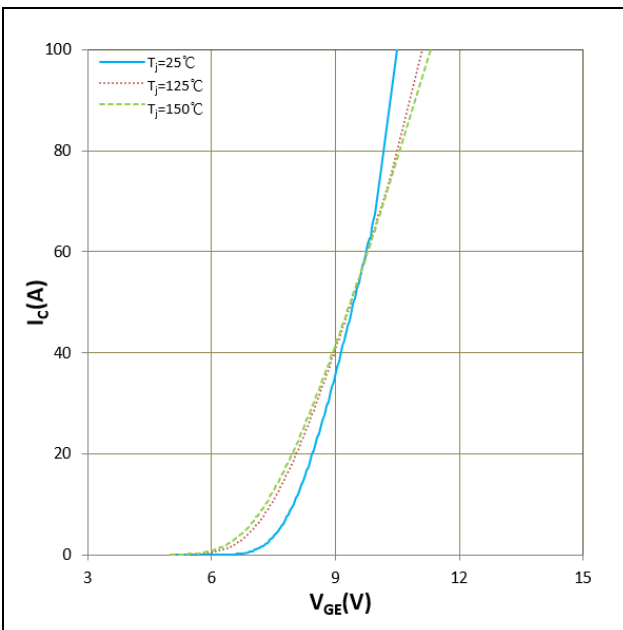


Figure 7. I_c vs V_{GE}
 $V_{CE}=20V$

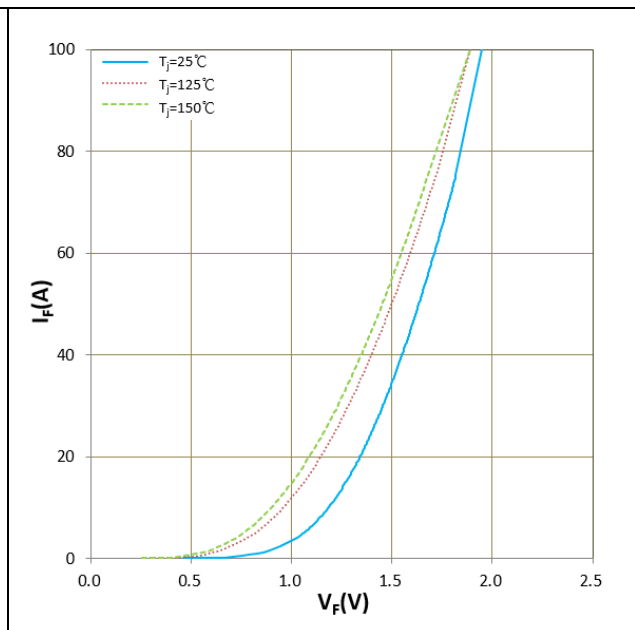


Figure 8. I_F vs V_F

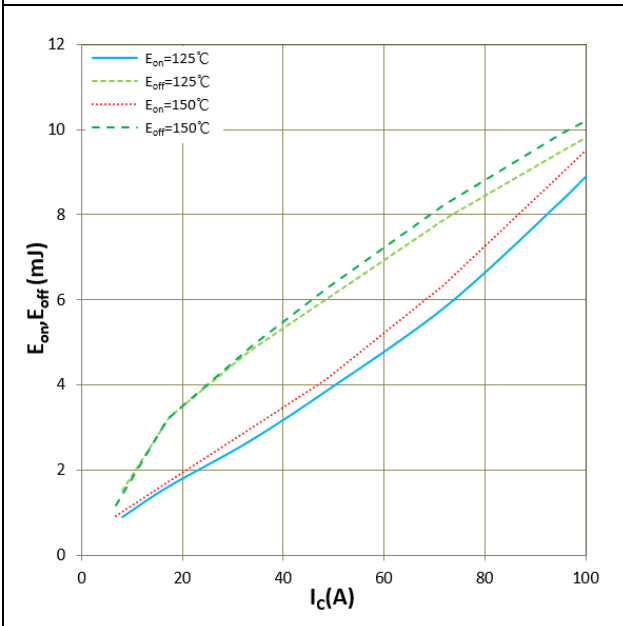


Figure 9. E_{on} , E_{off} vs I_c (Typ)
 $V_{CC}=600V$, $V_{GE}=+15V/-8V$, $R_{Gon} = R_{Goff}=10\Omega$
Inductive Load

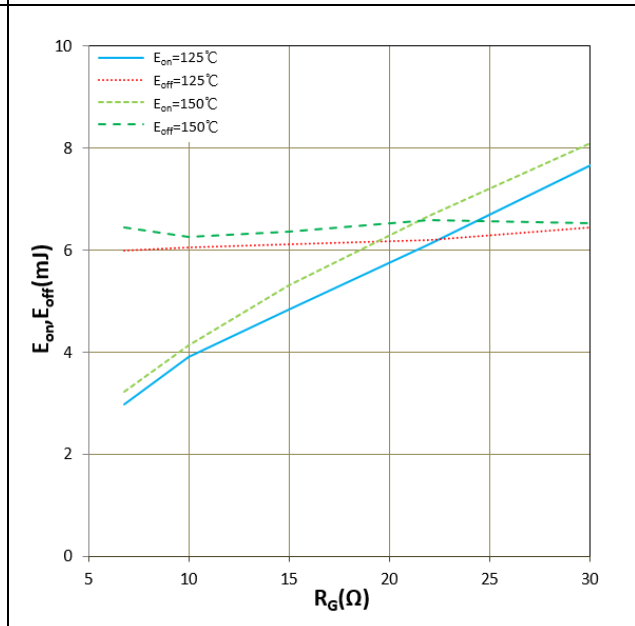
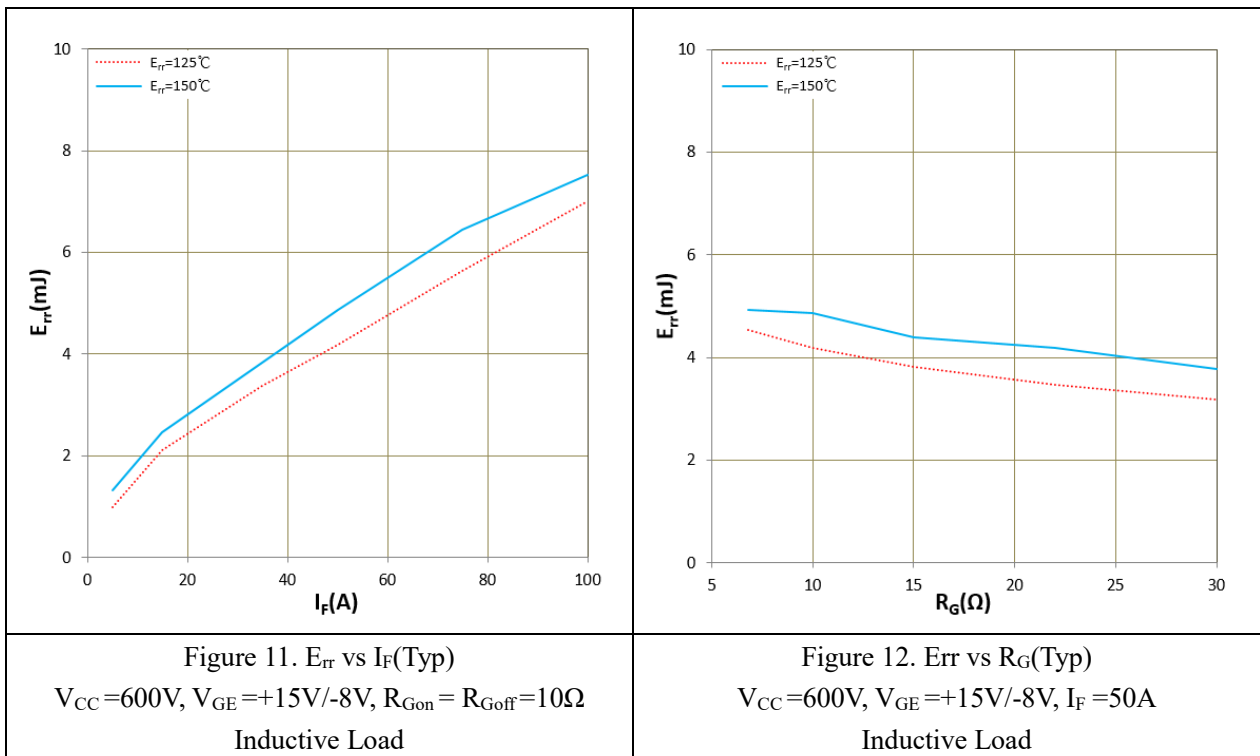


Figure 10. E_{on} , E_{off} vs R_G (Typ)
 $V_{CC}=600V$, $V_{GE}=+15V/-8V$, $I_c = 50A$
Inductive Load



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